



# AMP3003 SOLID STATE HIGH POWER AMPLIFIER

## FEATURES

- Class AB linear GaN design
- Instantaneous wide bandwidth
- Suitable for all modulations standards
- Built-in protection circuits
- High reliability and ruggedness



## ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	2.0 - 2.7 GHz	
Power Output	100 Watt Min	CW
Power Gain	50 dB Min	
Power Gain Flatness	4.0dB p-p Max	Constant input power
Gain Variation Over Temperature	±1.0 dB	Rated case temperature
Input / Output VSWR	2:1 / 2:1	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	>30 dBc Typ	37dBm/Tone, Δ = 1MHz
Harmonics	>20 dBc Typ	At rated Pout
Non Harmonics Spurious	>60 dBc Min	
Operating Voltage	28 VDC ± 0.5 V	
Current Consumption	12 Amp Max	At rated Pout
Max Input Power	+10 dBm	Without damage
Load VSWR Protection	∞ : 1	
Turn On / Off Speed	5 μSec Max	

## ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +75 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non Condensation

## MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	188 x 91.5 x 27 mm	Excluding Connectors
Weight	700 kg	Typical Weight
RF Connectors In/Out	SMA female	
DC Power / Interface Connector	9-Pin D-Sub	
Cooling	External Heatsink	Forced air required

## D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	FWD	N/C
2	REV	N/C
3	CURRENT SENSOR	I <sub>D</sub> @20mV/100mA Typ
4	TEMP SENSOR	V <sub>T</sub> @10mV/°C + 500mV Typ
5	SHUTDOWN	TTL
6, 7	VDD	28VDC
8, 9	GND	Ground

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## OUTLINE DRAWING

